

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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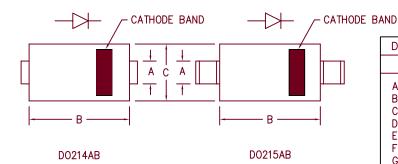
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



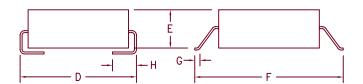




8 Amp Schottky Rectifier LSM835 — LSM845



Dim. Inches			Millimeter	
	Minimum	Maximum	Minimum	Maximum Notes
Α	.117	.123	2.97	3.12
В	.260	.280	6.60	7.11
С	.220	.245	5.59	6.22
D	.307	.322	7.80	8.18
E	.075	.095	1.91	2.41
F	.380	.400	9.65	10.16
G	.025	.040	.640	1.02
Н	.030	.060	.760	1.52



Microsemi Catalog Number	Working Working Peak Reverse Voltage	Repetitive Repetitive Peak Reverse Voltage
LSM835* LSM840* LSM845*	35V 40V 45V	35V 40V 45V
*Add Suffix J For	J Lead or G For Gull	Wing Lead Configuration

- Schottky Barrier Rectifier
- Guard Ring Protection
- Low Forward Voltage
- 150°C Junction Temperature
- VRRM 35 to 45 Volts
- High Current Capability

Electrical Characteristics

Average forward current
Maximum surge current
Max peak forward voltage
Max peak forward voltage
Max peak reverse current
Typical junction capacitance

I F(AV) 8.0 Amps I F(AV) 350 Amps V FM .40 Volts V FM .52 Volts I RM 2 mA CJ 575 pF Square wave
8.3 ms, half sine, TJ = 150 °C
IFM = 8.0A:TJ = 150 °C *
IFM = 8.0A:TJ = 25 °C *
VRRM, TJ = 25 °C
VR = 5.0V, TJ = 25 °C

* Pulse test: Pulse width 300 jusec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range Operating junction temp range Maximum thermal resistance Weight TSTG TJ ROJL -55°C to 175°C -55°C to 150°C 20°C/W Junction to lead .008 ounces (.22 grams) typical

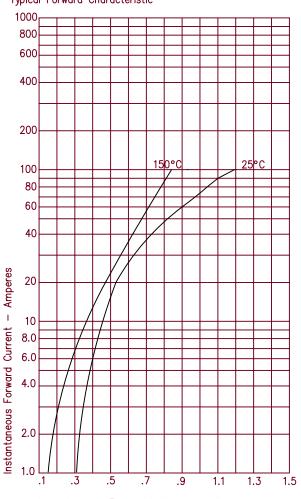


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LSM835 - LSM845

Figure 1 Typical Forward Characteristic



Instantaneous Forward Voltage — Volts

